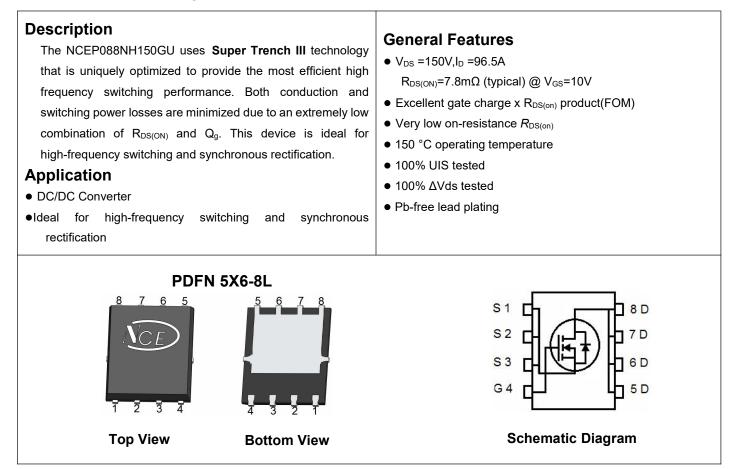


NCE N-Channel Super Trench III Power MOSFET



Package Marking and Ordering Information

| Device Marking | Device | Device Package | Reel Size | Tape width | Quantity |
|----------------|----------------|----------------|-----------|------------|----------|
| P088NH150GU | NCEP088NH150GU | DFN5X6-8L | - | - | - |

Absolute Maximum Ratings (Tc=25°C unless otherwise noted)

| Parameter | Symbol | Limit | Unit |
|--|-----------------------|------------|------|
| Drain-Source Voltage | Vds | 150 | V |
| Gate-Source Voltage | Vgs | ±20 | V |
| Drain Current-Continuous | ١ _D | 96.5 | A |
| Drain Current-Continuous(T _C =100 °C) | I _D (100℃) | 60.5 | A |
| Pulsed Drain Current | I _{DM} | 386 | A |
| Maximum Power Dissipation | PD | 180 | W |
| Derating factor | | 1.44 | W/℃ |
| Single pulse avalanche energy (Note 1) | E _{AS} | 501 | mJ |
| Operating Junction and Storage Temperature Range | TJ,TSTG | -55 To 150 | °C |

Thermal Characteristic

| | Thermal Resistance, Junction-to-Case | R _{ejc} | 0.7 | °C/W |
|--|--------------------------------------|------------------|-----|------|
|--|--------------------------------------|------------------|-----|------|



Electrical Characteristics (Tc=25 $^{\circ}$ C unless otherwise noted)

| Parameter | Symbol | Condition | Min | Тур | Max | Unit |
|------------------------------------|---------------------|---|-----|------|------|------|
| Off Characteristics | · , | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | V _{GS} =0V I _D =250µA | 150 | - | - | V |
| Zero Gate Voltage Drain Current | IDSS | V _{DS} =150V,V _{GS} =0V | - | - | 1 | μA |
| Gate-Body Leakage Current | I _{GSS} | V_{GS} =±20V, V_{DS} =0V | - | - | ±100 | nA |
| On Characteristics | · · · | | | | | |
| Gate Threshold Voltage | V _{GS(th)} | $V_{DS}=V_{GS}$, $I_{D}=250\mu A$ | 2.5 | 3.3 | 4.5 | V |
| Drain-Source On-State Resistance | R _{DS(ON)} | V_{GS} =10V, I _D =20A | - | 7.8 | 8.8 | mΩ |
| Forward Transconductance | g fs | V _{DS} =10V,I _D =40A | - | 30 | - | S |
| Dynamic Characteristics | I | | | | | |
| Input Capacitance | Clss | V _{DS} =75V,V _{GS} =0V, | - | 2738 | - | pF |
| Output Capacitance | Coss | | - | 932 | - | pF |
| Reverse Transfer Capacitance | Crss | F=1.0MHz | - | 30 | - | pF |
| Switching Characteristics (Note 2) | · · | | | | | |
| Turn-on Delay Time | t _{d(on)} | | - | 15 | - | nS |
| Turn-on Rise Time | tr | V _{DD} =75V,I _D =40A | - | 70 | - | nS |
| Turn-Off Delay Time | t _{d(off)} | V_{GS} =10V, R_{G} =4.7 Ω | - | 30 | - | nS |
| Turn-Off Fall Time | tf | | - | 10 | - | nS |
| Total Gate Charge | Qg | V _{DS} =75V,I _D =20A, | - | 48 | - | nC |
| Gate-Source Charge | Q _{gs} | | - | 15 | - | nC |
| Gate-Drain Charge | Q _{gd} | V _{GS} =10V | - | 14.5 | - | nC |
| Drain-Source Diode Characteristics | | | - | | | |
| Diode Forward Voltage | V _{SD} | V _{GS} =0V,I _F =20A | - | - | 1.2 | V |
| Diode Forward Current | Is | | - | - | 96.5 | A |
| Reverse Recovery Time | t _{rr} | T _J = 25°C, I _F = 40A | - | 88 | - | nS |
| Reverse Recovery Charge | Qrr | di/dt = 100A/µs | - | 222 | - | nC |

Notes:

1. EAS condition : Tj=25 $^\circ \!\! \mathbb{C}$,V_DD=50V,V_G=10V,L=0.5mH,Rg=25\Omega

2. Guaranteed by design, not subject to production

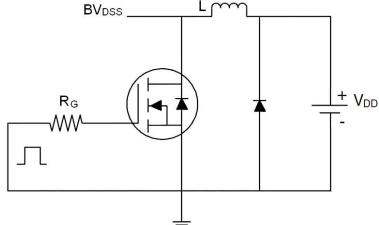
3. These curves are based on the junction-to-case thermal impedance which is measured with the device mounted to a large heatsink, assuming a maximum junction temperature of T_{J(MAX)}=150°C. The SOA curve provides a single pulse rating.



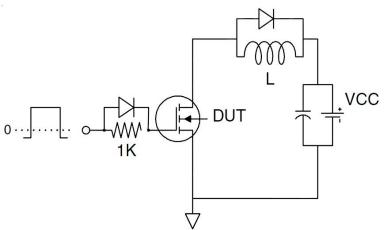
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Test Circuit

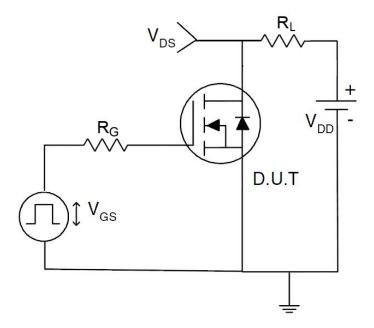
1) E_{AS} test Circuit



2) Gate charge test Circuit



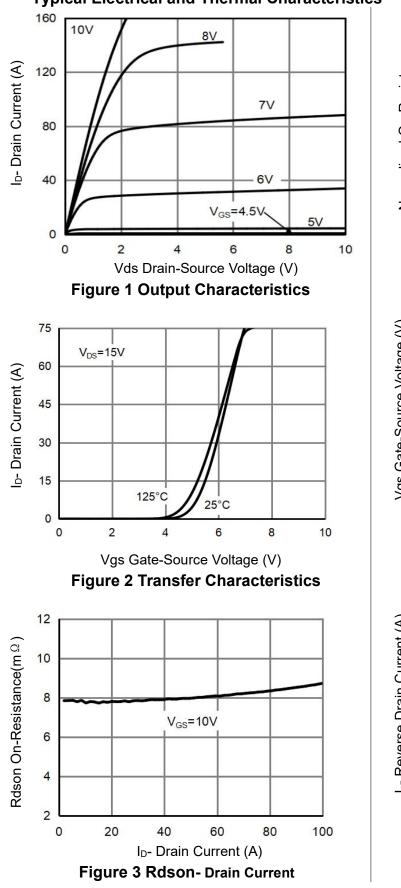
3) Switch Time Test Circuit

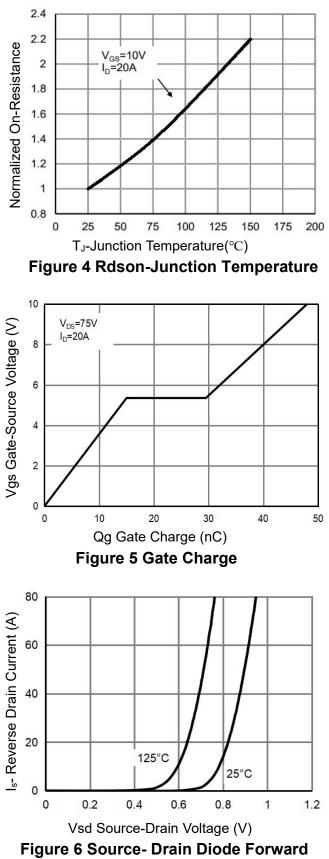




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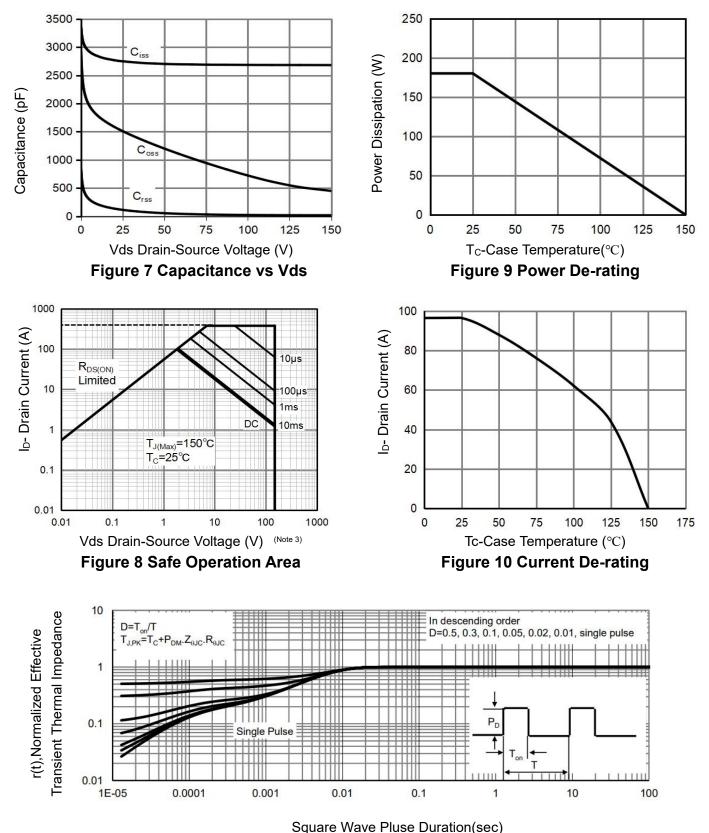
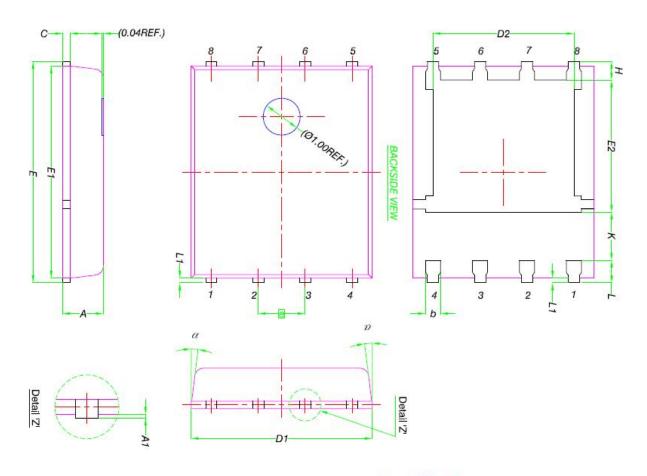


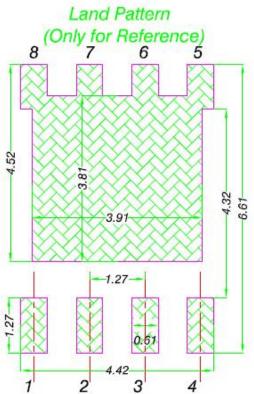
Figure 11 Normalized Maximum Transient Thermal Impedance



DFN5X6-8L Package Information



| - | MILLIMETERS | | | |
|------|-------------|------|------|--|
| DIM. | MIN. | NOM. | MAX. | |
| Α | 0.90 | 1.00 | 1.10 | |
| A1 | 0 | - | 0.05 | |
| b | 0.33 | 0.41 | 0.51 | |
| С | 0.20 | 0.25 | 0.30 | |
| D1 | 4.80 | 4.90 | 5.00 | |
| D2 | 3.61 | 3.81 | 3.96 | |
| Е | 5.90 | 6.00 | 6.10 | |
| E1 | 5.70 | 5.75 | 5.80 | |
| E2 | 3.38 | 3.58 | 3.78 | |
| е | 1.27 BSC | | | |
| Н | 0.41 | 0.51 | 0.61 | |
| К | 1.10 | (| | |
| L | 0.51 | 0.61 | 0.71 | |
| L1 | 0.06 | 0.13 | 0.20 | |
| α | 0° | - | 12 | |





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